Study of Physical Properties of Zn\(_{1-x}\)Ag\(_x\)O thin Films Deposited by Chemical Spray Pyrolysis

BHAWNA SARWAN\(^1, 2\) and AMAN DEEP ACHARYA\(^1, 2\)*

\(^1\)Department of Chemistry, Vikram University, Ujjain, 456010, MP, India.
\(^2\)Department of Physics. Lovely Professional University, Jalandhar, Punjab 144411, India.

*Corresponding author E-mail: acharyaphysics2011@gmail.com

http://dx.doi.org/10.13005/ojc/340560

(Received: July 18, 2018; Accepted: August 23, 2018)

ABSTRACT

To investigate the influence of Ag concentration on physical properties, the Zn\(_{1-x}\)Ag\(_x\)O films were synthesized by chemical spray pyrolysis method. The crystals size was found to decrease for low concentration of Ag then increase upto 50 nm with increase in Ag content. AFM measurement implies that the roughness and grain size increased due to coalescence of petite grains into larger size. In optical measurement, band gap is found to be decreased with increase in filler concentration.

Keywords: Thin film, ZnO, Spray pyrolysis method, Doping.

INTRODUCTION

ZnO is one of the most suitable metal oxide semiconductor having variety of applications, for instance transparent conducting oxides, photodetectors and Light emitting diodes because of its distinctive properties such as direct band gap, large exciton binding energy, excellent thermal and chemical stability, piezoelectric effect etc.\(^1-9\) Pure ZnO thin film, although transparent, are usually of low conductivity. Though, practical application of any semiconductor lies on effectual tuning of its physical properties. In order to tune the physical properties of the semiconductors doping is considered as the effective tool. However, n–type ZnO thin film with excellent conductive properties can be obtained by doping in neat ZnO.\(^10\) Doping of ZnO thin film with Al, Ga, Sc, Y, Mn, Cu, Ag etc. have been reported to improve its physical properties.\(^1\) Group I elements have a tendency to take up inside interstitial sites rather than substitution sites therefore they act as donors.\(^11\) Among these dopant Ag was elected as a dopant to study the effect on the physical properties of the film. There are several techniques physical as well as chemical which can be employed to fabricate doped and pure ZnO thin films such as laser deposition, different sputtering methods, atomic layer deposition, chemical vapor deposition, chemical bath deposition, sol–gel, and spray pyrolysis method.\(^12-18\)

The sputtering and evaporation techniques have been proved to be very exclusive and have some shortcoming such as target utilization effectiveness and arcing. Spray pyrolysis is a magnificent, elementary, resourceful and economically viable...
technique. In present work we report the structural studies, morphological and optical properties of Ag-doped ZnO thin films.

Sample preparation

\( \text{Zn}_{1-x} \text{Ag}_x \text{O} \) (\( x=0, 0.002, 0.0025, 0.005, 0.006, 0.0075, 0.01 \)) thin films were prepared by spray pyrolysis experimental technique. This setup is commonly used for deposition of oxide thin films. The zinc oxide thin films were synthesised by aqueous solution of 0.2 M zinc nitrate and silver nitrate is the precursor opted for Ag doping\(^{19}\). The optimization have been made by synthesizing the samples by varying temperatures from 200\( ^\circ \text{C} \) to 400\( ^\circ \text{C} \). After several trials the stable and sticky films were obtained at 400\( ^\circ \text{C} \). X-ray diffraction for structural studies is performed by using (Bruker D8 ADVANCE). Morphological study was done by using atomic force microscopy (AFM) (Digital instruments Nanoscope E with Si\(_3\)N\(_4\) 100 \( \mu\text{m} \) cantilever, 0.58 N/m force constant). Optical studies have been performed by using UV-Vis Spectrophotometer (Perkin Elmer Lambda 950) for the wavelength region from 300 nm to 900 nm.

RESULTS AND DISCUSSION

Structural Studies

Figure 1 shows the X-Ray diffraction (XRD) graph of \( \text{Zn}_{1-x} \text{Ag}_x \text{O} \) thin films for \( x = 0, x = 0.002, x = 0.0025, x = 0.005, x = 0.006, x = 0.0075 \) and \( x = 0.01 \). The XRD measurement of the deposited films reveal that the films have polycrystalline nature consisting with hexagonal structure in accordance with JCPDS files (PDF # 891397). The preferred orientation of the films is evidenced by the presence of (002) peak. The other diffraction peaks observed in the X-Ray pattern are (1 0 0), (1 0 1), (1 0 2), (1 1 0), (1 0 3) and (1 1 2), but the intensity of these peaks were obtained to be low as compared to the preferentially oriented (0 0 2) peak. Crystallite size is obtained with the help of eq. 1 (Debye Scherer formula)\(^{20}\)

\[
D = \frac{0.9 \lambda}{\beta \cos \theta}
\]  

(1)

It was observed that the crystallite size was decreased from 54 to 38 nm by increasing Ag content up to 0.25% but for further increase in Ag dopant concentration it increases (i.e 50 nm). This might be because of the larger ionic radius of Ag\(^+\) (126 pm) or Ag\(^{2+}\) (97 pm) as compare to Zn\(^{2+}\) (74 pm)\(^{21}\). Due to large difference in the ionic radius, the presence of Ag at Zn site leads to increase in strain of the film (see Fig. 2). The relation used to calculate the strain is as follows (Eq. 2);

\[
\text{Strain} = \frac{\beta \cos \theta}{4}
\]  

(2)

Where \( \beta \) is full width at half maximum of XRD peak and \( \theta \) is angle of diffraction. From the graph, we can see that initially with small Ag doping concentration, the strain was increased but as the Ag doping concentration increased the strain was reduced. The above stated conclusion confirmed the successful incorporation of the filler (Ag) into the ZnO lattice.

Morphological Studies

The surface studies of \( \text{Zn}_{1-x} \text{Ag}_x \text{O} \) films have been done by using Atomic Force Microscopy
displayed in Fig. 3. From AFM images, it was observed that the grain size as well as roughness was constantly enhanced with increment of Ag content. The larger grains build up due to coalescence of petite grains into bigger size (Fig. 3). This result evidenced that Ag doping contributed in grain expansion in a course of action that the several tiny grains coalesce simultaneously to form bigger sized grains.

Optical Studies

The optical property of the deposited films was investigated by using UV–Vis spectroscopy. Fig. 4 shows the transmittance spectrum of the Zn$_{1-x}$Ag$_x$O thin films with respect to wavelength ranges from 300 nm to 900 nm. The obtained curve shows the better transmittance in visible region, whereas low transmittance is observed in UV region. As a whole it was examined that the transmittance decreased with increasing filler content.

The absorbance was found to increase with the Ag content as shown in Fig. 5a. The optical band gap $E_g$ has been determined by Tauc relation (Eq. 5)

\[
(\alpha h\nu) = A (h\nu - E_g)^n
\]

Here $h\nu$ is the photon energy, $A$ is proportional constant related to material and `$n$' is ½ for direct allowed transition and 2 for indirect allowed transition. As ZnO was direct band gap...
thus n=1/2 is expected to direct allowed transition. A graph showing the $(\alpha h\nu)^2$ versus $(h\nu)$ is plotted in Fig. 5b. It was observed from the figure that initially a slight increment has been found in band gap but for the higher doping concentration the band gap was reduced up to 2.9 eV. The probable cause behind the slight increment has been found in band gap but for the higher doping concentration the band gap was reduced up to 2.9 eV. The probable cause behind the decreasing trend of the band gap at the later stage might be due to band shrinkage effect because of increase in filler concentration.

**CONCLUSION**

Ag-doped ZnO films were synthesized by chemical spray pyrolysis system. XRD results shows that all the films were polycrystalline having a hexagonal wrutzite type structure. The as-prepared films show preferential growth in (0 0 2) plane. The crystallite size was decreased at low dopant concentration and then increased with increase in Ag content. AFM measurement suggests that both the roughness and grain size was increased due to coalescence of delicate grains into larger size. The optical measurement shows reduction in transmittance by adding Ag concentration because of enhancement in mobility and charge carrier concentration.

**ACKNOWLEDGMENT**

Authors would like to express gratitude to the Center Director of UGC-DAE CSR, Indore for their assistance and support to take advantage of available experimental facilities.

**REFERENCES**

8. Nam, Sang-Hun; Kim, Myoung-Hwa; Yoo, Dong Geun; Jeong, Seong Hun; Kim, Doo Yong; Lee, Nae-Eung; Boo, J.-H. Surf. Rev. Lett., 2010, 17, 121-127.
10. Guan, Li.; Liu, Baoting; Li, Qiang; Zhou, Yang; Guo, Jianxin; Jia, Guoqi; Zhao, Qingxun; Wang, Yinglong; Fu, Guangsheng Phys. Lett., A. 2011, 375, 939-945.